TOSHIBA Transistor Silicon PNP Epitaxial Type

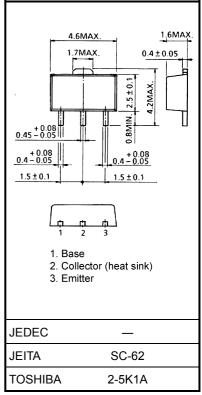
2SA2059

High-Speed Switching Applications DC-DC Converter Applications Strobe Applications

- High DC current gain: $h_{FE} = 200$ to 500 (I_C = -0.5 A)
- Low collector-emitter saturation voltage: V_{CE} (sat) = -0.19 V (max)
- High-speed switching: $t_f = 40 \text{ ns}$ (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-20	V	
Collector-emitter voltage		V _{CEO}	-20	V	
Emitter-base voltage		V _{EBO}	-7	V	
Collector current	DC	Ι _C	-3.0	A	
	Pulse	I _{CP}	-5.0		
Base current		I _B	-300	mA	
Collector power dissipation	DC	P _C	1.0	W	
	t = 10 s	(Note)	2.5		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.05 g (typ.)

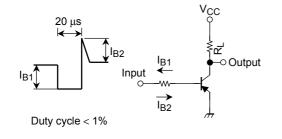
Note: Mounted on FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current		I _{CBO}	$V_{CB} = -20 V, I_E = 0$	_	_	-100	nA	
Emitter cut-off current		I _{EBO}	V _{EB} = -7 V, I _C = 0	_	_	-100	nA	
Collector-emitter breakdown voltage		V (BR) CEO	$I_{\rm C} = -10$ mA, $I_{\rm B} = 0$	-20	_	_	V	
DC current gain		h _{FE} (1)	V _{CE} = -2 V, I _C = -0.5 A	200	_	500		
		h _{FE} (2)	V _{CE} = -2 V, I _C = -1.6 A	100	_	_		
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = −1.6 A, I _B = −53 mA	_	_	-0.19	V	
Base-emitter saturation voltage		V _{BE (sat)}	I _C = −1.6 A, I _B = −53 mA	_	_	-1.10	V	
Collector output capacitance		C _{ob}	V _{CB} = −10 V, I _E = 0, f = 1 MHz	_	28	_	pF	
Switching time	Rise time	t _r	See Figure 1 circuit diagram.	_	70	_	ns	
	Storage time	t _{stg}	$V_{CC} \approx -12 \text{ V}, \text{ R}_{L} = 7.5 \Omega$	_	150	_		
	Fall time	t _f	−I _{B1} = I _{B2} = −53.3 mA		40	—		

Unit: mm

Marking



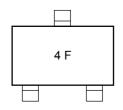
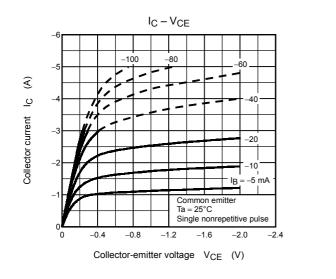
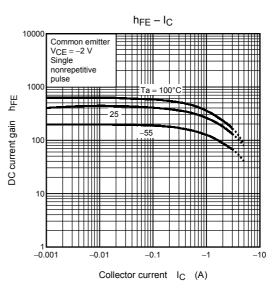
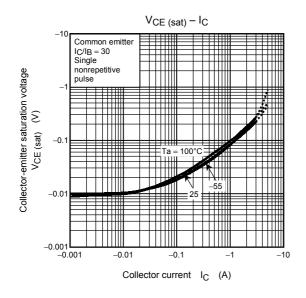


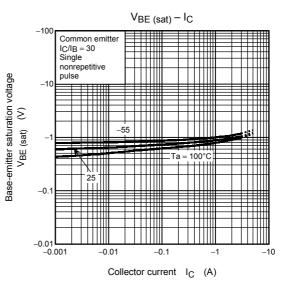
Figure 1 Switching Time Test Circuit & Timing Chart

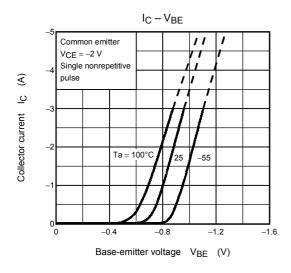
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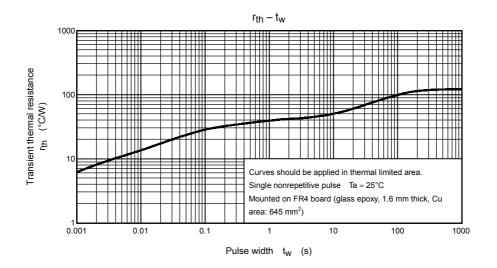












Safe Operating Area -10 0 μs**•** I_C max (pulsed) ♦ 10 ms♦ 1 ms♦ 100 μs♦ 10 µs♦ IC max (continuous) € 100 ms♦ <u>ں</u> 10 s♦* DC operation * Collector current (Ta = 25°C) Content of the second sec -0.7 T VCEO r with increase in temperature. -0.01 -10 -100 Collector-emitter voltage V_{CE} (V)

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